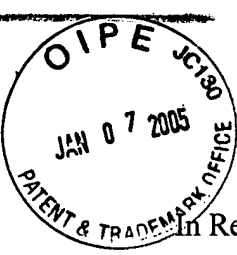


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Attorney Docket SEL 147-CON



**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In Re Application of )  
)  
Hisashi OHTANI )  
)  
Serial No.: 09/916,913 )  
)  
Filed: July 27, 2001 )  
)  
For: Thin Film Transistor Formed )  
On A Resin Substrate )  
)  
Art Unit: 2825 )  
)  
Examiner: L. Malsawma )  
)  
Confirm no. )

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to:  
Commissioner for Patents ,  
P.O. Box 1450, Alexandria, VA 22313-1450 on

January 4, 2005  
(Date of Deposit)

Shannon Wallace

Name of applicant, assignee, or Registered Rep.

Shannon Wallace 1/4/05  
Signature Date

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**AMENDMENT I (AFTER ALLOWANCE AND PAYMENT OF ISSUE FEE)**

Sir:

In response to the Notice of Allowance of September 22, 2004 and in furtherance of Amendment H filed December 22, 2004 with the payment of the issue fee, please amend the above-identified application as follows: